## NSN 5961-01-390-0168

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Inclosure Material: Metal Overall Length: Between 0.170 inches and 0.210 inches Overall Diameter: Between 0.209 inches and 0.230 inches Internal Configuration: Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 Electrode Internally-electrically Connected To Case: Source
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Electrode Internally-electrically Connected To Case:
Source
Course
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-25.0 drain to source voltage and 10.0 gate to source voltage
Current Rating Per Characteristic:
-30.00 milliamperes drain current
Power Rating Per Characteristic:
375.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0